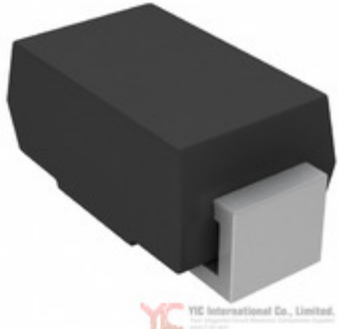
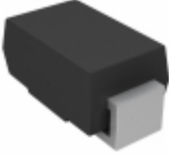
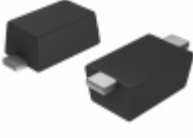
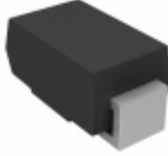

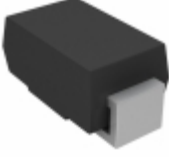
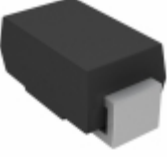
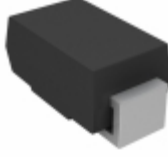
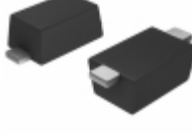
	<h2>US1BHE3/61T</h2>
	<p>Hersteller-Teilenummer: US1BHE3/61T</p> <p>Hersteller / Marke: Vishay / Semiconductor - Diodes Division</p> <p>Teil der Beschreibung: DIODE GEN PURP 100V 1A DO214AC</p> <p>Datenblätter: 1.US1BHE3/61T.pdf 2.US1BHE3/61T.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 130000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	US1BHE3/61T
Hersteller	Vishay / Semiconductor - Diodes Division
Beschreibung	DIODE GEN PURP 100V 1A DO214AC
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	130000 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	DO-214AC, SMA
Supplier Device-Gehäuse	DO-214AC (SMA)
Diodentyp	Standard
Strom - Richt (Io)	1A
Spannung - Forward (Vf) (Max) @ If	1V @ 1A
Strom - Sperrleckstrom @ Vr	10µA @ 100V
Spannung - Sperr (Vr) (max)	100V
Geschwindigkeit	Fast Recovery = 200mA (Io)
Rückwärts-Erholzeit (Trr)	50ns
Betriebstemperatur - Anschluss	-55°C ~ 150°C
Kapazität @ Vr, F	15pF @ 4V, 1MHz
Verpackung	Tape & Reel (TR)

US1BHE3/61T ist neu im Original, Suche US1BHE3/61T Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie US1BHE3/61T Vishay / Semiconductor - Diodes Division mit Garantie und Vertrauen. Anfrage US1BHE3/61T: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>US1BHE3_A/H Vishay / Semiconductor - Diodes Division DIODE FAST REC 100V 1A DO214AC</p>	 <p>US1BFA Fairchild/ON Semiconductor DIODE GEN PURP 100V 1A SOD123FA</p>	 <p>US1BHE3_A/I Electro-Films (EFI) / Vishay DIODE GEN PURP 100V 1A DO214AC</p>	 <p>US1BHM2G TSC (Taiwan Semiconductor) DIODE GEN PURP 100V 1A DO214AC</p>
 <p>US1BHE3/61T Electro-Films (EFI) / Vishay DIODE GEN PURP 100V 1A DO214AC</p>	 <p>US1BHE3/5AT Electro-Films (EFI) / Vishay DIODE GEN PURP 100V 1A DO214AC</p>	 <p>US1BHE3_A/I Vishay / Semiconductor - Diodes Division DIODE FAST REC 100V 1A DO214AC</p>	 <p>US1BFA AMI Semiconductor / ON Semiconductor DIODE GEN PURP 100V 1A SOD123FA</p>

heiße Teile

Mehr

⊗ US1881KSO	↔ US1881KUA	⇒ US1881KUA-AAA-000-BU	D US1881LSO	↔ US1A-13-F
⊥ US1A-E3/5AT	⊗ US1A-E3/5AT	D US1A-E3/61T	⇒ US1A-E3/61T	↔ US1A-M3/61T
⊗ US1A-M3/61T	⊥ US1AHE3/5AT	⊗ US1AHE3/5AT	↔ US1AHE3/61T	↔ US1AHE3/61T
D US1B-13-F	⊗ US1B-E3/5AT	⊥ US1B-E3/5AT	⊗ US1B-E3/61T	↔ US1B-E3/61T
⇒ US1B-M3/61T	↔ US1B-M3/61T	⊗ US1BHE3/5AT	⊥ US1BHE3/5AT	↔ US1BHE3/61T
↔ US1C-E3/61T	⇒ US1D-13-F	D US1D-E3/61T	⊗ US1D-E3/61T	⊥ US1D-M3/61T
⊗ US1D-M3/61T	D US1DWF-7	⇒ US1DWF-7	↔ US1G-13-F	↔ US1G-E3/61T
⊥ US1G-E3/61T	⊗ US1G-M3/61T	↔ US1G-M3/61T	⇒ US1G/11T	↔ US1GHE3/5AT
⊗ US1GHE3/5AT	⊥ US1GHE3/61	⊗ US1GHE3/61T	D US1GHE3/61T	↔ US1GHE3_A/H
↔ US1GHE3_A/H	⊗ US1GWF-7	⊥ US1GWF-7	⊗ US1J-13-F	↔ US1J-5AT

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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